

Pin Assignments

PGND

IN 3

PGND

2 GND



5 OUT

FB

GND

FB

4

6

4

0.6V ADJUSTABLE PRECISION SHUNT REGULATOR

Top view

SC70-5/SOT353, TSOT23-5

Top view

### Description

The ZXRE060 is a 5-terminal adjustable shunt regulator offering excellent temperature stability and output handling capability. The ZXRE060 simplifies the design of isolated low voltage DC-DC regulators. With its low 0.6V FB pin, it can control the regulation of rails as low 0.6V. This makes it ideal for state of the art microprocessor/DSP and PLD core voltage POL converters.

The device open-collector output can operate from 0.2V to 18V and regulated output voltage can be set by selection of two external divider resistors.

Separating the input from the open collector output enables the ZXRE060 to be used to make low-cost low drop-out regulators operating at low input voltages.

The ZXRE060 is available in two grades with initial tolerances of 0.5% and 1% for the A and standard grades respectively. It is available in space saving low profile 5 pin SC70-5/SOT353, thin TSOT23-5 and very small DFN1520H4-6 packages.

The ZXRE060 in TSOT23-5 has its OUT, GND and FB pins matching the Cathode, Anode and reference pins of the TL432 and TLV431 in SOT23-3, thereby facilitating simple upgrade paths.

### Features

- Low Reference Voltage (V<sub>FB</sub> = 0.6V)
- -40 to +125°C Temperature Range
- Reference Voltage Tolerance at +25°C
  - 0.5% ZXRE060A
  - ZXRE060 1%
- **Typical Temperature Drift** 
  - <4mV (0°C to +70°C)
  - <6mV (-40°C to +85°C)
  - <12mV (-40°C to +125°C)
  - 0.2V to 18V Open-collector Output
- High Power Supply Rejection
- >45dB at 300kHz
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)



1

DFN1520H4-6

### Applications

- Isolated DC-DC Converters
- Core Voltage POL
- Low Voltage Low-Dropout Linear Regulators
- Shunt Regulators
- Adjustable Voltage Reference
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:
  - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

# **Typical Application Circuit**





## Pin Description

Pin Number (SC70-5 /SOT353, TSOT23-5)	Pin Number (DFN1520H4-6)	Pin Name	Function
1	1	PGND	Power Ground: Ground return for emitter of output transistor: Connect PGND and GND together.
_	2	N/C	No connection
5	3	OUT	Output. Connect a capacitor close to device between OUT and GND. See the Applications Information section.
4	4	FB	Feedback Input. Regulates to 600mV nominal.
2	5	GND	Analog Ground: Ground return for reference and amplifier: Connect GND and PGND together.
3	6	IN	Supply Input. Connect a $0.1 \mu F$ ceramic capacitor close to the device from IN to GND.
_	Flag	_	Floating or connect to GND

## **Function Block Diagram**



The ZXRE060 differs from most other shunt regulators in that it has separate input and output pins and a low voltage reference. This enables it to regulate rails down to 600mV and makes the part ideal for isolated power supply applications that use opto-couplers in the feedback loop and where the open-collector output is required to operate down to voltages as low as 200mV.

The wide input voltage range of 2V to 18V and output voltage range of 0.2V to 18V enables the ZXRE060 to be powered from an auxiliary rail, while controlling a master rail which is above the auxiliary rail voltage, or below the minimum  $V_{IN}$  voltage. This allows it to operate as a low-dropout voltage regulator for microprocessor/DSP/PLD cores.

As with other shunt regulators (and shunt references), the ZXRE060 compares its internal amplifier FB pin to a high accuracy internal reference; if FB is below the reference then OUT turns off, but if FB is above the reference then OUT sinks current – up to a maximum of 15mA.



## Absolute Maximum Ratings (Voltages to GND Unless Otherwise Stated)

Symbol	Parameter	Rating	Unit
VIN	IN Voltage relative to GND	20	V
Vout	OUT Voltage relative to GND	20	V
V <sub>FB</sub>	FB Voltage relative to GND	20	V
PGND	PGND Voltage relative to GND	-0.3 to +0.3	V
IOUT	OUT Pin Current	20	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>ST</sub>	Storage Temperature	55 to +150	Do.

These are stress ratings only. Operation outside the absolute maximum ratings may cause device failure. Operation at the absolute maximum rating for extended periods may reduce device reliability.

Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.

## Package Thermal Data

Package	θ <sub>JA</sub>	P <sub>DIS</sub> T <sub>A</sub> = +25°C, T <sub>J</sub> = +150°C
SC70-5/SOT353	400°C/W	310mW
TSOT23-5	250°C/W	500mW
DFN1520H4-6	TBD	ТВД

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Мах	Unit
VIN	IN Voltage Range (0 to +125°C)	2	18	
V <sub>IN</sub>	IN Voltage Range (-40 to 0°C)	2.2	18	V
Vout	OUT Voltage Range	0.2	18	
I <sub>OUT</sub>	OUT Pin Current	0.3	15	mA
TA	Operating Ambient Temperature Range	-40	+125	°C





## Electrical Characteristics (@T<sub>A</sub> = +25°C, V<sub>IN</sub> = 3.3V, V<sub>OUT</sub> = V<sub>FB</sub>, I<sub>OUT</sub> = 5mA, unless otherwise stated. (Note 4))

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
		ZXRE060A	0.597	0.6	0.603			
		—	ZXRE060	0.594	0.6	0.606	V	
		T. 0°C to 195°C	ZXRE060A	0.595	_	0.605		
Vfb		$T_A = 0^{\circ}C$ to +85°C	ZXRE060	0.592	_	0.608		
VFB	Feedback Voltage	T <sub>A</sub> = -40°C to +85°C	ZXRE060A	0.594		0.606		
		$T_A = -40^{\circ} \text{C} 10^{\circ} + 65^{\circ} \text{C}$	ZXRE060	0.591	_	0.609		
		T <sub>A</sub> = -40°C to +125°C	ZXRE060A	0.593	/	0.607		
		$T_A = -40 \text{ C} 10 + 125 \text{ C}$	ZXRE060	0.590		0.610		
FBLOAD	Feedback Pin Load Regulation	IOUT = 1 to 15mA	_	X	3.8	6	mV	
FBLOAD	reeuback Fill Load Regulation		T <sub>A</sub> = -40 to +125°C			10	IIIV	
FBLINE	Feedback Pin Line Regulation	V <sub>IN</sub> = 2V to 18V	_		0.1	1		
I DLINE		V <sub>IN</sub> = 2.2V to 18V	T <sub>A</sub> = -40 to +125°C	_		1.5	mV	
FBOVR	Output Voltage Regulation	V <sub>OUT</sub> = 0.2V to 18V,		—		1	mV	
PBOAK		I <sub>OUT</sub> = 1mA	T <sub>A</sub> = -40 to +125°C		A	1.5	IIIV	
I <sub>FB</sub>	FB Input Bias Current	V <sub>IN</sub> = 18V	_	-	-45	—	nA	
IFB		VIN = 10V	T <sub>A</sub> = -40 to +125°C	-200	-	0		
		V <sub>IN</sub> = 2V to 18V			0.35	0.7	0.7	
		V <sub>IN</sub> = 2.2V to 18V	$T_A = -40 \text{ to } +125^{\circ}\text{C}$			1	mA	
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = 2V to 18V		_	0.48	1		
		V <sub>IN</sub> = 2.2V to 18V	T <sub>A</sub> = -40 to +125°C			1.5	mA	
		V <sub>IN</sub> = 18V,	_			0.1		
I <sub>OUT(LK)</sub>	OUT Leakage Current	V <sub>OUT</sub> = 18V, V <sub>FB</sub> = 0V	T <sub>A</sub> = +125°C	_	_	1	μA	
Z <sub>OUT</sub> Dynamic Outpu	Dunamia Qutaut Imagdagaa	louт = 1 to 15mA		_	0.25	0.4	0	
	Dynamic Output Impedance	f < 1kHz	T <sub>A</sub> = -40 to +125°C	—	_	0.6	Ω	
PSRR	Power Supply Rejection Ratio	f = 300kHz V <sub>AC</sub> = 0.3V <sub>PP</sub>	_	—	>45	—	dB	
BW	Amplifier Unity Gain Frequency	Ref: Figure 1		_	600	_	kHz	
G	Amplifier Transconductance			—	5000		mA/V	

Note:

4. Production testing of the device is performed at +25°C. Functional operation of the device and parameters specified over the operating temperature range are guaranteed by design, characterisation and process control.



# **Typical Characteristics**





**ZXRE060** 

## **Typical Operating Conditions (Cont.)**







## Application Information

The following show some typical application examples for the ZXRE060. It is recommended to include the compensation capacitor C2 to guarantee stability. C2 may range in value from 0.1µF to 10µF depending on the application. The time constant formed by C2 and R3 should be greater than 1ms multiplied by the feedback factor R2/(R1 + R2).

Both C1 and C2 should be as close to the ZXRE060 as possible and connected to it with the shortest possible track. In the case of Figure 8 and Figure 9, it means the opto-coupler will have to be carefully positioned to enable this.



Design Guides

- 1. Determine I<sub>OUT</sub> and choose a suitable transistor taking power dissipation into consideration.
- Determine I<sub>B</sub> from  $I_B = \frac{I_{OUI(max)}}{(hFE(min) + 1)}$ 2.
- Determine  $I_{R3}$  from  $I_{R3} \ge I_B + I_{KA(min)}$ . The design of the ZXRE060 effectively means there is no  $I_{KA(min)}$  limitation as in conventional 3. references. There is only an output leakage current which is a maximum of 1µA. Nevertheless, it is necessary to determine an  $I_{KA(min)}$  to ensure that the device operates within its linear range at all times.  $I_{KA(min)} \ge 10\mu A$  should be adequate for this. 4.
  - Determine R3 from  $R3 = \frac{V_{IN} (V_{OUT} + V_{BE})}{V_{IN} (V_{OUT} + V_{BE})}$ . I<sub>R3</sub>
- 5. Although unlikely to be a problem, ensure that  $I_{R3} \le 15$ mA.



 $V_{OUT} = V_{REF} \left( 1 + \frac{R1}{R2} \right)$ 

 $(V_{OUT} \ge 0.2V + V_{BE})$ 

I<sub>R3</sub>

 $R3 = \frac{V_{IN} - V_{OUT}}{V_{IN} - V_{OUT}}$ 

# Application Information (Cont.)



Figure 6. 1V Current-boosted Shunt Regulator

**Design Guides** 

- 1. Determine I<sub>OUT</sub> and choose a suitable transistor taking power dissipation into consideration.
- 2. Determine I<sub>B</sub> from  $I_B = \frac{IOUT(max)}{(hFE(min) + 1)}$
- 3. Determine  $I_{R3}$  from  $I_{R3} = I_{OUT(max)}$
- 4. Determine R3 from  $R3 = \frac{V_{IN} V_{OUT}}{V_{IN} V_{OUT}}$
- It is best to let the ZXRE060 supply as much current as it can before bringing Q1 into conduction. Not only does this minimise the strain on Q1, it also guarantees the most stable operation. Choose a nominal value between 10mA and <15mA for this current, I<sub>R4</sub>.
- 6. Calculate R4 from  $R4 = \frac{V_{BE}}{I_{R4}}$



VOUT goes low and LED is lit when monitored supply

$$V_{M} > V_{REF} \left(1 + \frac{R1}{R2}\right)$$
$$R3 = \frac{V_{IN} - (V_{F} + 0.2)}{I_{R3}}$$

 $15mA \ge I_{R3} \le I_{F(MAX)}$ 

 $V_{\mathsf{F}}$  and  $I_{\mathsf{F}}$  are forward voltage drop and current of LED1.

Figure 7. 1.15V Over-voltage Indicator



### Application Information (Cont.)



 $R3 = \frac{V_{IN} - (V_F + 0.2)}{V_{IN} - (V_F + 0.2)}$ I<sub>R3</sub>  $15mA \ge I_{R3} \le I_{F(MAX)}$ 

V<sub>F</sub> and I<sub>F</sub> are forward voltage drop and forward current respectively for the optocoupler LED.

More applications information is available in the following publications which can be found on Diodes Incorporated's web site.

- AN58 Designing with Diodes Incorporated's References Shunt Regulation AN59 Designing with Diodes Incorporated's References Series Regulation
- AN60 Designing with Diodes Incorporated's References *Fixed Regulators and Opto-Isolation* AN61 Designing with Diodes Incorporated's References *Extending the operating voltage range* AN62 Designing with Diodes Incorporated's References *Other Applications* AN63 Designing with Diodes Incorporated's References *ZXRE060 Low Voltage Regulator*



## Ordering Information



Tol.	Order Code	Package	Identification Code	Reel Size	Tape Width	Quantity/Reel
	ZXRE060AET5TA	TSOT23-5	S6A	7", 180mm	8mm	3000
0.5%	ZXRE060AH5TA	SC70-5/SOT353	S6A	7", 180mm	8mm	3000
	ZXRE060AFT4-7	DFN1520H4-6	S6A	7", 180mm	8mm	3000
	ZXRE060ET5TA	TSOT23-5	S06	7", 180mm	8mm	3000
1%	ZXRE060H5TA	SC70-5/SOT353	S06	7", 180mm	8mm	3000
	ZXRE060FT4-7	DFN1520H4-6	S06	7", 180mm	8mm	3000

Note: 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

(1) TSOT23-5, SC70-5/SOT353



(2) DFN1520H4-6

### (Top View)

(	
<b>6 6</b>	XXX : Identification code
	<u> Y</u> : Year : 0~9
	<u>W</u> : Week : A~Z : 1~26 week;
YWX	a~z : 27~52 week;
	z : represents 52 and 53
	$\underline{X}$ : A~Z : Internal Code



**ZXRE060** 

## **Package Outline Dimensions**

### (1) TSOT23-5





#### (2) SC70-5/SOT353

A1



SOT-353					
Dim	Dim Min Max				
A	0.10	0.30			
В	1.15	1.35			
C	2.00	2.20			
Ď	0.65	Тур			
F	0.40	0.45			
н	1.80	2.20			
J	0	0.10			
K	0.90	1.00			
L	0.25	0.40			
М	0.10	0.22			
α	0°	8°			
All Dimensions in mm					

### (3) DFN1520H4-6



	DFN1520H4-6					
Dim	Min	Max	Тур			
Α	_	0.40	_			
A1	0	0.05	-			
A3	_	-	0.13			
b	0.20	0.30	-			
D	1.45	1.575	-			
D2	1.00	1.20	-			
e	-	-	0.50			
E	1.95	2.075	_			
E2	0.70	0.90	-			
L	0.25	0.35	_			
All Dimensions in mm						



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